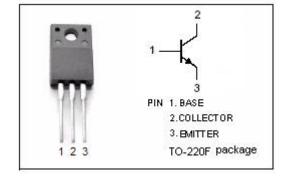


## isc Silicon NPN Power Transistor

KTD2059

## **DESCRIPTION**

- · Collector-Emitter Breakdown Voltage-
- : V<sub>(BR)CEO</sub>= 100V(Min)
- · Collector Power Dissipation-
  - : P<sub>C</sub>= 30W@ T<sub>C</sub>= 25℃
- · Low Collector Saturation Voltage-
  - :  $V_{CE(sat)}$ = 2.0V(Max)@ (I<sub>C</sub>= 4A, I<sub>B</sub>= 0.4A)
- Complement to Type KTB1367
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

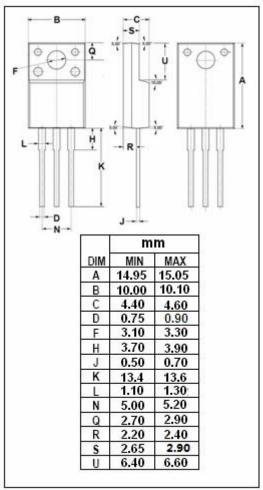


#### **APPLICATIONS**

· Designed for general purpose applications.

# ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>СВО</sub>	Collector-Base Voltage	100	V
Vceo	Collector-Emitter Voltage	100	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
Ic	Collector Current-Continuous	5	А
I <sub>B</sub>	Base Current-Continuous	0.5	А
Pc	Collector Power Dissipation @T <sub>C</sub> =25°C	30	W
TJ	Junction Temperature	150	$^{\circ}$ C
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$





## **ISC Silicon NPN Power Transistor**

KTD2059

#### **ELECTRICAL CHARACTERISTICS**

Tj=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 50mA; I <sub>B</sub> = 0	100			V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 4A; I <sub>B</sub> = 0.4A			2.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V			1.5	V
I <sub>CBO</sub>	Collector Cutoff Current	V <sub>CB</sub> = 100V; I <sub>E</sub> = 0			100	μ <b>А</b>
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V; I <sub>C</sub> = 0			1	mA
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V	40		240	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 4A; V <sub>CE</sub> = 5V	20			

#### ♦ h<sub>FE-1</sub> Classifications

R	0	Y
40-80	70-140	120-240

#### **NOTICE:**

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